



U74LVC125A

CMOS IC

QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS

DESCRIPTION

The **U74LVC125A** consists of four bus buffers with 3-state output controlled by enable input (\overline{OE}), when \overline{OE} is high, the output is disable.

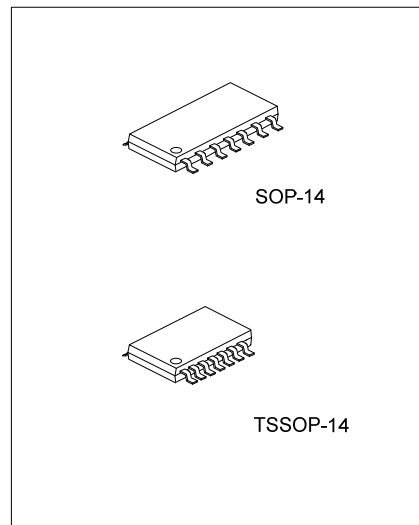
Inputs can be driven from either 3.3V or 5V devices, so the device can be used in a mix 3.3V/5V system.

FEATURES

- * Operation Voltage Range: 1.65~3.6V
- * Low Power Dissipation
- * Input Accept Voltage to 5.5V

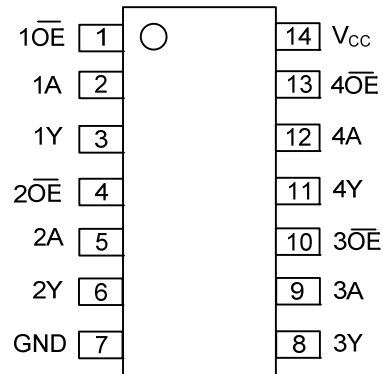
ORDERING INFORMATION

Ordering Number		Package	Packing
Lead Free	Halogen Free		
U74LVC125AL-S14-R	U74LVC125AG-S14-R	SOP-14	Tape Reel
U74LVC125AL-P14-R	U74LVC125AG-P14-R	TSSOP-14	Tape Reel



<p>U74LVC125AL-S14-R</p> <p>(1) Packing Type (2) Package Type (3) Lead Free</p>	<p>(1) R: Tape Reel (2) S14: SOP-14, P14: TSSOP-14 (3) L: Lead Free, G: Halogen Free</p>
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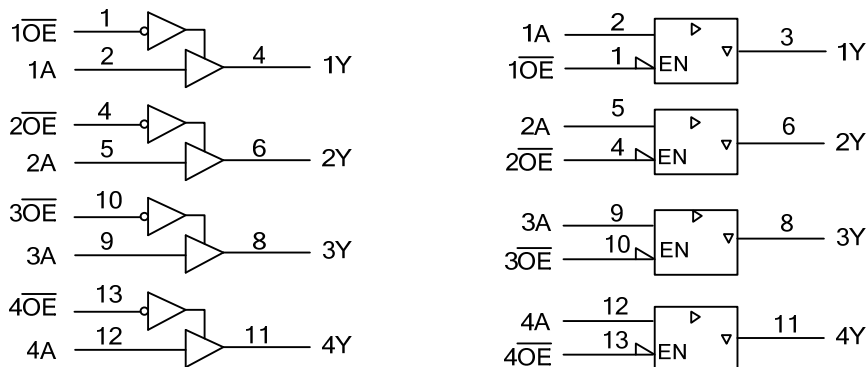
■ PIN CONFIGURATION



■ FUNCTION TABLE (each gate)

INPUT		OUTPUT
\overline{OE}	A	Y
L	L	L
L	H	H
H	X	Z

■ LOGIC DIAGRAM (positive logic)



■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{CC}	-0.5~6.5	V
Input Voltage	V_{IN}	-0.5~6.5	V
Output Voltage(active mode)	V_{OUT}	-0.5~ $V_{CC}+0.5$	V
Input Clamp Current($V_{IN}<0$)	I_{IK}	-50	mA
Output Clamp Current($V_O<0$)	I_{OK}	-50	mA
Output Current	I_{OUT}	± 50	mA
V_{CC} or GND Current	I_{CC}	± 100	mA
Power Dissipation	P_D	500	mW
Storage Temperature	T_{STG}	-65 ~ +150	$^{\circ}C$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}	Operating	1.65		3.6	V
		Data retention only	1.5			
Input Voltage	V_{IN}		0		5.5	V
Output Voltage	V_{OUT}		0		V_{CC}	V
Input Rise or Fall Times	t_R, t_F				8	ns/V
Operating Temperature	T_A		-40		125	$^{\circ}C$

■ STATIC CHARACTERISTICS ($T_a=25^{\circ}C$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
High-Level Input Voltage	V_{IH}	$V_{CC}=1.65V \sim 1.95V$	$0.65^* V_{CC}$			V
		$V_{CC}=2.3V \sim 2.7V$	1.7			V
		$V_{CC}=2.7V \sim 3.6V$	2			V
Low-Level Input Voltage	V_{IL}	$V_{CC}=1.65V \sim 1.95V$			$0.35^* V_{CC}$	V
		$V_{CC}=2.3V \sim 2.7V$			0.7	V
		$V_{CC}=2.7V \sim 3.6V$			0.8	V
High-Level Output Voltage	V_{OH}	$V_{CC}=1.65V \sim 3.6V, I_{OH}=-100\mu A$	$V_{CC}-0.2$			V
		$V_{CC}=1.65V, I_{OH}=-4mA$	1.29			V
		$V_{CC}=2.3V, I_{OH}=-8mA$	1.9			V
		$V_{CC}=2.7V, I_{OH}=-12mA$	2.2			V
		$V_{CC}=3V, I_{OH}=-12mA$	2.4			V
Low-Level Output Voltage	V_{OL}	$V_{CC}=1.65V \sim 3.6V, I_{OL}=100\mu A$			0.1	V
		$V_{CC}=1.65V, I_{OL}=4mA$			0.24	V
		$V_{CC}=2.3V, I_{OL}=8mA$			0.3	V
		$V_{CC}=2.7V, I_{OL}=12mA$			0.4	V
		$V_{CC}=3V, I_{OL}=24mA$			0.55	V
Input Leakage Current	$I_{I(LEAK)}$	$V_{CC}=3.6V, V_{IN}=5.5V$ or GND			± 1	μA
Output OFF-State current	I_{OZ}	$V_{CC}=3.6V, V_{OUT}=V_{CC}$ or GND			± 1	μA
Quiescent Supply Current	I_Q	$V_{CC}=3.6V, V_{IN}=V_{CC}$ or GND $I_{OUT}=0$			1	μA
Additional Quiescent Supply Current	ΔI_Q	$V_{CC}=2.7V \sim 3.6V$, One input at $V_{CC}-0.6V$, other inputs at V_{CC} or GND			500	μA
Input Capacitance	C_{IN}	$V_{CC}=3.3V, V_{IN}=V_{CC}$ or GND		5		pF

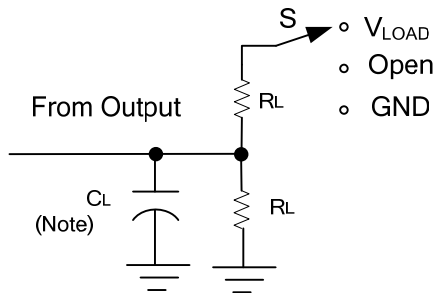
■ DYNAMIC CHARACTERISTICS (T_A=25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Propagation delay from input (A) to output (Y)	t _{PLH} /t _{PHL}	V _{CC} = 1.8V±0.15V	1	4.5	11.8	ns
		V _{CC} = 2.5V±0.2V	1	2.7	5.8	ns
		V _{CC} = 2.7V	1	3	5.3	ns
		V _{CC} = 3.3V±0.3V	1	2.5	4.6	ns
Propagation delay from input ($\overline{\text{OE}}$) to output (Y)	t _{PZL} /t _{PZH}	V _{CC} = 1.8V±0.15V	1	4.3	13.8	ns
		V _{CC} = 2.5V±0.2V	1	2.7	6.9	ns
		V _{CC} = 2.7V	1	3.3	6.4	ns
		V _{CC} = 3.3V±0.3V	1	2.4	5.2	ns
Propagation delay from input ($\overline{\text{OE}}$) to output (Y)	t _{PLZ} /t _{PHZ}	V _{CC} = 1.8V±0.15V	1	4.3	10.6	ns
		V _{CC} = 2.5V±0.2V	1	2.2	5.1	ns
		V _{CC} = 2.7V	1	2.5	4.8	ns
		V _{CC} = 3.3V±0.3V	1	2.4	4.4	ns

■ OPERATING CHARACTERISTICS (T_A=25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C _{pd}	V _{CC} =1.8V, f=10MHz		7.4		pF
		V _{CC} =2.5V, f=10MHz		11.3		pF
		V _{CC} =3.3V, f=10MHz		15		pF

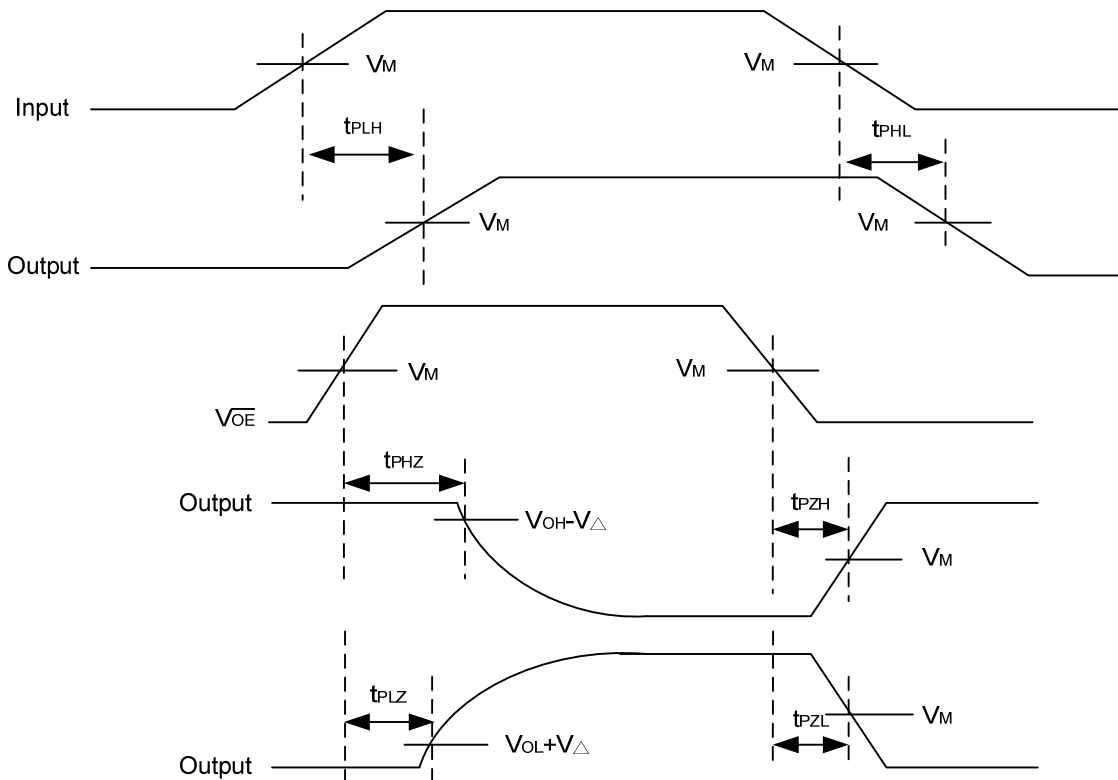
■ TEST CIRCUIT AND WAVEFORMS



TEST	S
t_{PLH}/t_{PHL}	Open
t_{PHZ}/t_{PZH}	GND
t_{PLZ}/t_{PZL}	V_{LOAD}

Note: C_L includes probe and jig capacitance.

V_{CC}	V_{IN}	t_{R}/t_F	V_M	V_{LOAD}	C_L	R_L	V_{Δ}
$1.8V \pm 0.15V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 * V_{CC}$	30pF	1K Ω	0.15V
$2.5V \pm 0.2V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 * V_{CC}$	30pF	500 Ω	0.15V
2.7V	2.7V	$\leq 2.5ns$	1.5V	6V	50pF	500 Ω	0.3V
$3.3V \pm 0.3V$	2.7V	$\leq 2.5ns$	1.5V	6V	50pF	500 Ω	0.3V



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